RP512Zxx1x-TR-F is discontinued product.

NISSHINBO

RP512x Series

0.3 µA I_Q Ultra-low Quiescent Current 300 mA Buck DC/DC Converter

No. EA-400-241106

OVERVIEW

RP512x is a DC/DC converter featuring 0.3 µA ultra-low operating quiescent current.
It is suitable for use in wearable and IoT devices that require miniaturization and long-lifetime of battery.

KEY BENEFITS

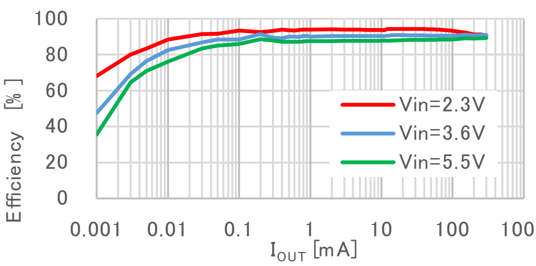
- VFM (f_{SW} up to 1 MHz) control achieves 0.3 µA ultra-low operating quiescent current.
- The wide range of V_{IN} from 2.0 V to 5.5 V allows operation from coin cell to USB port.
- Total mount area including C_{IN}, C_{OUT}, and inductor is 10.6 mm^2.
- Selectable packages including WLCSP, DFN, and SOT. 0.4 mm-thickness WLCSP package adaptable to IC cards.

KEY SPECIFICATIONS

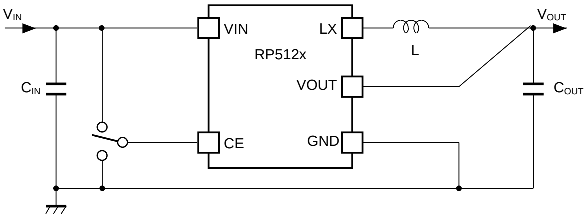
- Output Current: 300 mA
- Output Voltage Range:
  1.0 V to 4.0 V (Settable in 0.1 V step)
- Output Voltage Accuracy:
  ±1.5% ($V_{SET} \geq 1.2$ V), ±18 mV ($V_{SET} < 1.2$ V)
- Built-in Driver On-resistance (V_{IN} = 3.6 V):
  Typ. PMOS 0.15 Ω, NMOS 0.15 Ω (RP512Z)
- Standby Current: 0.01 µA

TYPICAL CHARACTERISTICS

V_{OUT} = 1.8 V



TYPICAL APPLICATIONS



L: 2.2 µH, C_{OUT}: 22 µF

SELECTION GUIDE

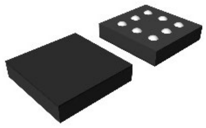
Product Name	Package	Q'ty per Reel
RP512Zxx1\$-TR-F	WLCSP-8-P1	5,000 pcs
RP512Zxx1\$-TR-T	WLCSP-8-P1	5,000 pcs
RP512Kxx1\$-TR	DFN2527(PL)-10	5,000 pcs
RP512Hxx1\$-T1-FE	SOT-89-5	1,000 pcs

xx: Set output voltage (V_{SET})
Fixed Output Voltage Type:
1.0 V (10) to 4.0 V (40) in 0.1 V step.

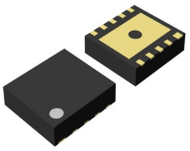
\$: Version

Version	Auto-discharge Function	V_{SET}
C	No	1.0 V to 4.0 V
D	Yes	

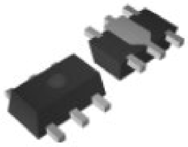
PACKAGES



WLCSP-8-P1
1.45 mm x 1.48 mm,
t=0.4mm (max.)



DFN(PL)2527-10
2.7mm x 2.5 mm,
t=0.6mm (max.)



SOT-89-5
4.5mm x 4.35mm,
t=1.6mm (max.)

APPLICATIONS

- Wearable equipment such as SmartWatch, SmartBand, and health monitoring
- Li-ion battery-used equipment, Coin cell-used equipment
- Low power RF such as *Bluetooth*® Low Energy, Zigbee, WiSun, and ANT
- Low power CPU, memory, sensor devices, and energy harvesting

SELECTION GUIDE

The set output voltage, the output voltage type, and the auto-discharge function(1), and the package for the ICs are user-selectable options.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP512Zxx1$-TR-F	WLCSP−8−P1	5,000 pcs	Yes	Yes
RP512Zxx1$-TR-T	WLCSP−8−P1	5,000 pcs	Yes	Yes
RP512Kxx1$-TR	DFN(PL)2527-10	5,000 pcs	Yes	Yes
RP512Hxx1$-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes

xx: Designation of the set output voltage (V_{SET})

For Fixed Output Voltage Type(2): 1.0 V (10) to 4.0 V (40) in 0.1 V step

$: Designation of Version

Version	Auto-discharge Function	V_{SET}
C	Disable	1.0 V to 4.0 V
D	Auto-discharge	

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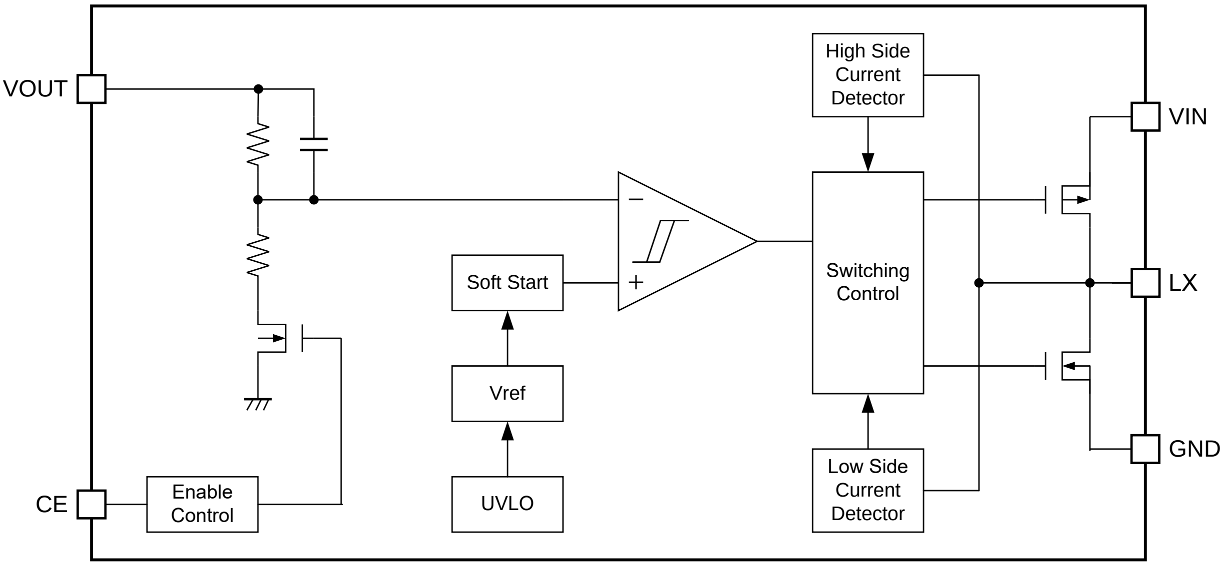
(1) Auto-discharge function quickly lowers the output voltage to 0 V, when the chip enable signal is switched from the active mode to the standby mode, by releasing the electrical charge accumulated in the external capacitor.

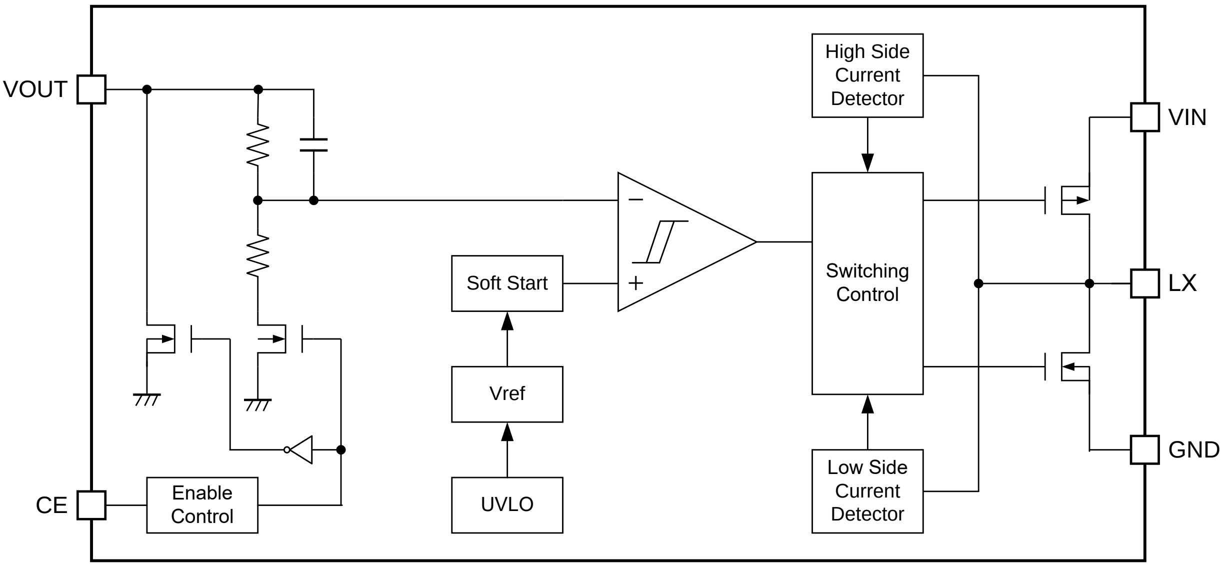
(2) The customization of specifying in 0.05 V step is available.

RP512Zxx1x-TR-F is discontinued product.

BLOCK DIAGRAM

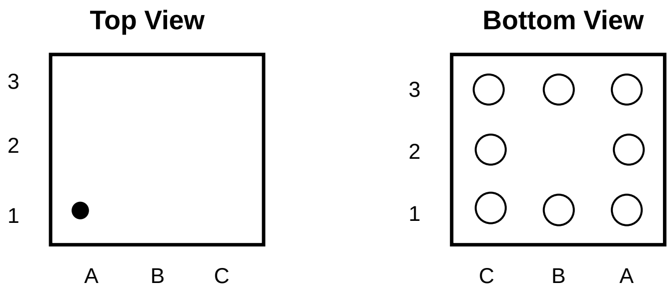


RP512xxx1C Block Diagram

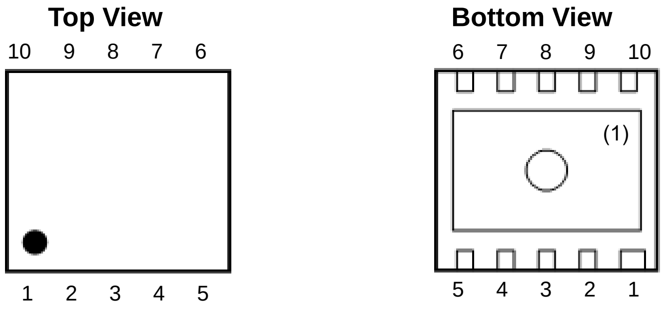


RP512xxx1D Block Diagram

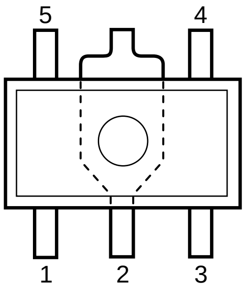
PIN DESCRIPTION



RP512Z (WLCSP-8-P1) Pin Configuration



RP512K [DFN(PL)2527-10] Pin Configuration



RP512H (SOT-89-5) Pin Configuration

RP512Z Pin Description

Pin No.	Symbol	Description
A1	VIN	Input Pin
B1	VIN	Input Pin
C1	LX	Switching Pin
A2	VOUT	Output voltage Pin
C2	GND	Ground Pin
A3	CE	Chip Enable Pin (Active-high)
B3	GND	Ground Pin
C3	GND	Ground Pin

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(1) The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.

RP512K Pin Description

Pin No.	Symbol	Description
1	VOUT	Output Pin
2	GND	Ground Pin
3	GND	Ground Pin
4	LX	Switching Pin
5	LX	Switching Pin
6	VIN	Input Pin
7	VIN	Input Pin
8	NC	No connection
9	CE	Chip Enable Pin (Active-high)
10	NC	No connection

RP512H Pin Description

Pin No.	Symbol	Description
1	VOUT	Output Pin
2	GND	Ground Pin
3	LX	Switching Pin
4	VIN	Input Pin
5	CE	Chip Enable Pin (Active-high)

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings (GND = 0 V)

Symbol	Parameter		Rating	Unit
V_{IN}	Input Voltage		−0.3 to 6.5	V
V_{LX}	LX Pin Voltage		−0.3 to V_{IN} + 0.3	V
V_{CE}	CE Pin Voltage		−0.3 to 6.5	V
V_{MODE}	MODE Pin Voltage		−0.3 to 6.5	V
V_{OUT}	VOUT Pin Voltage		−0.3 to 6.5	V
I_{LX}	LX Pin Output Current		650	mA
P_D	Power Dissipation[1]	WLCSP-8-P1, JEDEC STD. 51-9	1140	mW
		DFN(PL)2527-10, JEDEC STD. 51-7	2500	mW
		SOT-89-5, JEDEC STD. 51-7	2600	mW
Tj	Junction Temperature Range		−40 to 125	°C
Tstg	Storage Temperature Range		−55 to 125	°C

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the lifetime and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Conditions

Symbol	Parameter	Rating	Unit
V_{IN}	Input Voltage	2.0 to 5.5	V
Ta	Operating Temperature Range	−40 to 85	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

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[1] Refer to *POWER DISSIPATION* for detailed information.

ELECTRICAL CHARACTERISTICS

The specifications surrounded by $\boxed{\quad}$ are guaranteed by design engineering at -40°C ≤ Ta ≤ 85°C.

RP512x Electrical Characteristics (Ta = 25°C)

Symbol	Parameter		Condition		Min.	Typ.	Max.	Unit
V_{OUT}	Output Voltage		V_{IN} = V_{CE} = 3.6 V (V_{SET} ≤ 2.6 V), V_{IN} = V_{CE} = V_{SET} +1 V (V_{SET} > 2.6 V)	V_{SET} ≥ 1.2 V	x 0.985		x 1.015	V
				V_{SET} < 1.2 V	−0.018		+0.018	
I_Q	Operating Quiescent Current		V_{IN} = V_{CE} = V_{OUT} = 3.6 V, V_{SET} = 1.8 V, device not switching			0.3		µA
$I_{STANDBY}$	Standby Current		V_{IN} = 5.5 V, V_{CE} = 0 V			0.01	$\boxed{0.5}$	µA
I_{CEH}	CE Pin Input Current, high		V_{IN} = V_{CE} = 5.5 V		$\boxed{-0.025}$	0	$\boxed{0.025}$	µA
I_{CEL}	CE Pin Input Current, low		V_{IN} = 5.5 V, V_{CE} = 0 V		$\boxed{-0.025}$	0	$\boxed{0.025}$	µA
I_{VOUTH}	V_{OUT} "High" Input Current		V_{IN} = V_{OUT} = 5.5 V, V_{CE} = 0 V		$\boxed{-0.025}$	0	$\boxed{0.025}$	µA
I_{VOUTL}	V_{OUT} "Low" Input Current		V_{IN} = 5.5 V, V_{CE} = V_{OUT} = 0 V		$\boxed{-0.025}$	0	$\boxed{0.025}$	µA
R_{DISN}	Auto-discharge NMOS On-state Resistance(1)		V_{IN} = 3.6 V, V_{CE} = 0 V			60		Ω
V_{CEH}	CE Pin Input Voltage, high		V_{IN} = 5.5 V		$\boxed{1.0}$			V
V_{CEL}	CE Pin Input Voltage, low		V_{IN} = 2.0 V				$\boxed{0.4}$	V
R_{ONP}	PMOS On-state Resistance	RP512Z	V_{IN} = 3.6 V, I_{LX} = −100 mA			0.15		Ω
		RP512K	V_{IN} = 3.6 V, I_{LX} = −100 mA			0.19		Ω
		RP512H	V_{IN} = 3.6 V, I_{LX} = −100 mA			0.19		Ω
R_{ONN}	NMOS On-state Resistance	RP512Z	V_{IN} = 3.6 V, I_{LX} = −100 mA			0.15		Ω
		RP512K	V_{IN} = 3.6 V, I_{LX} = −100 mA			0.19		Ω
		RP512H	V_{IN} = 3.6 V, I_{LX} = −100 mA			0.19		Ω
t_{START}	Soft-start Time		V_{IN} = V_{CE} = 3.6 V (V_{SET} ≤ 2.6 V), V_{IN} = V_{CE} = V_{SET} + 1 V (V_{SET} > 2.6 V)			10		ms
I_{LXLIM}	LX Current Limit		V_{IN} = V_{CE} = 3.6 V (V_{SET} ≤ 2.6 V), V_{IN} = V_{CE} = V_{SET} + 1 V (V_{SET} > 2.6 V)		$\boxed{300}$	580		mA
V_{UVLOF}	Undervoltage Lockout (UVLO) Threshold		V_{IN} = V_{CE}, Falling		$\boxed{1.40}$	1.50	$\boxed{1.65}$	V
V_{UVLOR}			V_{IN} = V_{CE}, Rising		$\boxed{1.55}$	1.65	$\boxed{1.80}$	V

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj ≈ Ta = 25°C).
Test circuit is operated with “Open Loop Control” (GND = 0 V), unless otherwise specified.

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(1) RP512xxx1D only

Product-specific Electrical Characteristics

RP512xxx1x (Ta = 25°C)

Product Name	V_{OUT}		
	Min.	Typ.	Max.
RP512x101x	0.9820	1.00	1.0180
RP512x111x	1.0820	1.10	1.1180
RP512x121x	1.1820	1.20	1.2180
RP512x131x	1.2805	1.30	1.3195
RP512x141x	1.3790	1.40	1.4210
RP512x151x	1.4775	1.50	1.5225
RP512x161x	1.5760	1.60	1.6240
RP512x171x	1.6745	1.70	1.7255
RP512x181x	1.7730	1.80	1.8270
RP512x191x	1.8715	1.90	1.9285
RP512x201x	1.9700	2.00	2.0300
RP512x211x	2.0685	2.10	2.1315
RP512x221x	2.1670	2.20	2.2330
RP512x231x	2.2655	2.30	2.3345
RP512x241x	2.3640	2.40	2.4360
RP512x251x	2.4625	2.50	2.5375
RP512x261x	2.5610	2.60	2.6390
RP512x271x	2.6595	2.70	2.7405
RP512x281x	2.7580	2.80	2.8420
RP512x291x	2.8565	2.90	2.9435
RP512x301x	2.9550	3.00	3.0450
RP512x311x	3.0535	3.10	3.1465
RP512x321x	3.1520	3.20	3.2480
RP512x331x	3.2505	3.30	3.3495
RP512x341x	3.3490	3.40	3.4510
RP512x351x	3.4475	3.50	3.5525
RP512x361x	3.5460	3.60	3.6540
RP512x371x	3.6445	3.70	3.7555
RP512x381x	3.7430	3.80	3.8570
RP512x391x	3.8415	3.90	3.9585
RP512x401x	3.9400	4.00	4.0600

THEORY OF OPERATION

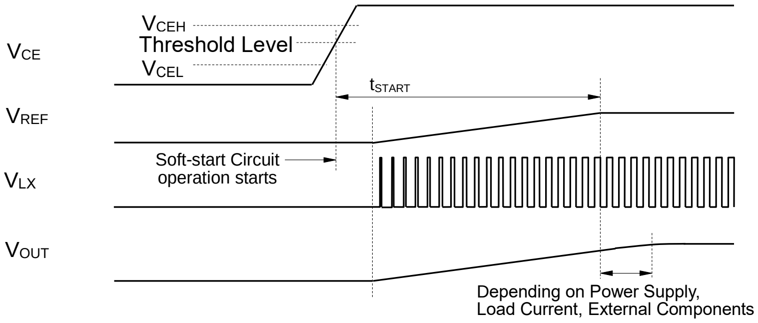
Soft-start Time

Starting-up with CE Pin

The IC starts to operate when the CE pin voltage (V_{CE}) exceeds the threshold voltage. The threshold voltage is preset between CE "H" input voltage (V_{CEH}) and CE "Low" input voltage (V_{CEL}).

After the start-of the start-up of the IC, soft-start circuit starts to operate. Then, after a certain period of time, the reference voltage (V_{REF}) in the IC gradually increases up to the specified value.

Notes: Soft start time (t_{START})(1) is not always equal to the turn-on speed of the step-down DC/DC converter. Please note that the turn-on speed could be affected by the power supply capacity, the output current, the inductance value and the C_{OUT} value.

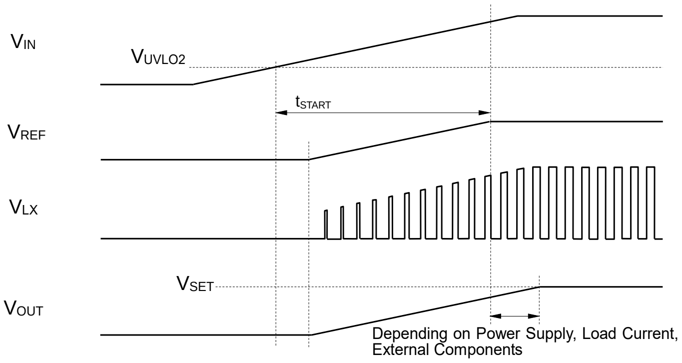


Timing Chart when Starting-up with CE Pin

Starting-up with Power Supply

After the power-on, when V_{IN} exceeds the UVLO released voltage (V_{UVLO2}), the IC starts to operate. Then, soft-start circuit starts to operate and after a certain period of time, V_{REF} gradually increases up to the specified value.

Note: Please note that the turn-on speed of V_{OUT} could be affected by the power supply capacity, the output current, the inductance value, the C_{OUT} value and the turn-on speed of V_{IN} determined by C_{IN}.



Timing Chart when Starting-up with Power Supply

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[1] Soft-start time (t_{START}) indicates the duration until the reference voltage (V_{REF}) reaches the specified voltage after soft-start circuit's activation.

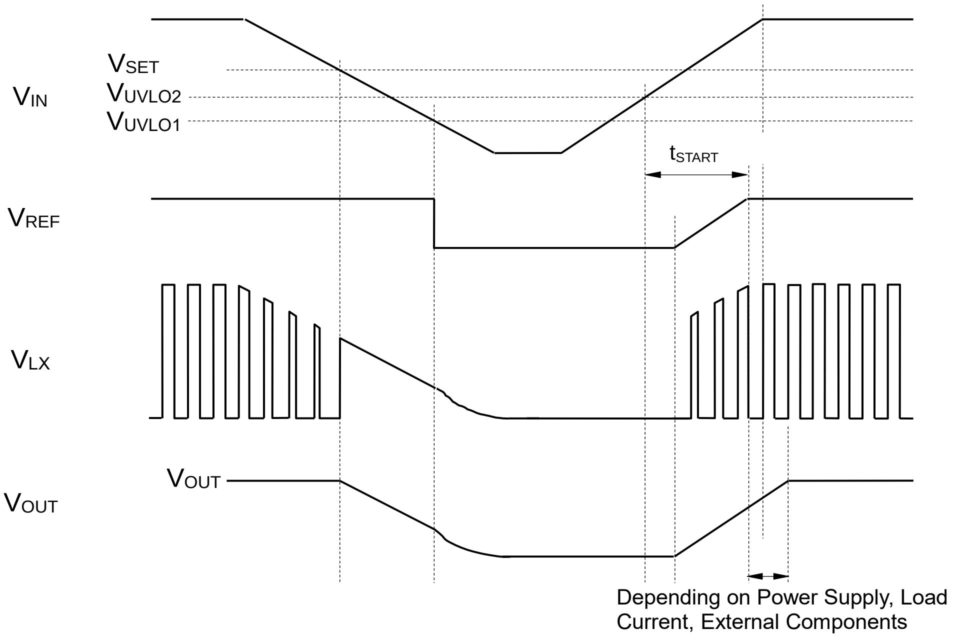
Undervoltage Lockout (UVLO) Circuit

If V_{IN} becomes lower than V_{SET}, the step-down DC/DC converter stops the switching operation and ON duty becomes 100%, and then V_{OUT} gradually drops according to V_{IN}. If the V_{IN} drops more and becomes lower than the UVLO detector threshold (V_{UVLO1}), the UVLO circuit starts to operate, V_{REF} stops, and PMOS and NMOS built-in switch transistors turn "OFF". As a result, V_{OUT} drops according to the C_{OUT} capacitance value and I_{OUT}.

As for RP512xxx1D, the discharge transistor for C_{OUT} discharges after it turns on. To restart the operation, V_{IN} needs to be higher than V_{UVLO2}.

The timing chart below shows the voltage shifts of V_{REF}, V_{LX} and V_{OUT} when V_{IN} value is varied.

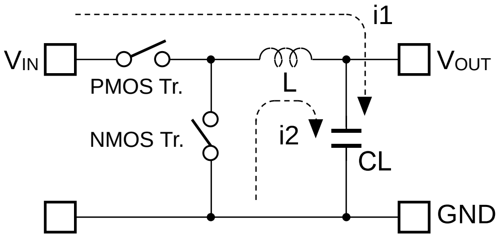
Note: Falling edge (operating) and rising edge (releasing) waveforms of V_{OUT} could be affected by the initial voltage of C_{OUT} and the output current of V_{OUT}.



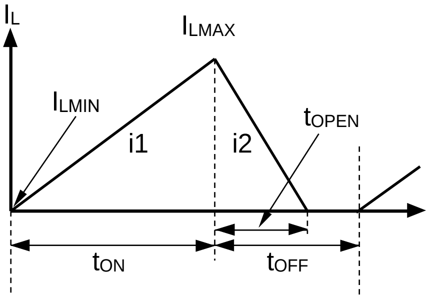
Timing Chart with Variations in Input Voltage (V_{IN})

Operation of Step-down DC/DC Converter and Output Current

The step-down DC/DC converter charges energy in the inductor when LX transistor turns “ON”, and discharges the energy from the inductor when LX transistor turns “OFF” and controls with less energy loss, so that a lower output voltage (V_{OUT}) than the input voltage (V_{IN}) can be obtained. The operation of the step-down DC/DC converter is explained in the following figures.



Basic Circuit



Inductor Current (IL) flowing through Inductor (L)

Step1. PMOS transistor turns “ON” and I_L (i1) flows, L is charged with energy. At this moment, i1 increases from the minimum inductor current (I_{LMIN}), which is 0 A, and reaches the maximum inductor current (I_{LMAX}) in proportion to the on-time period (t_{ON}) of PMOS transistor.

Step2. When PMOS transistor turns “OFF”, L tries to maintain I_L at I_{LMAX}, so L turns NMOS transistor “ON” and I_L (i2) flows into L.

Step3. i2 decreases gradually and reaches I_{LMIN} after the open-time period (t_{OPEN}) of NMOS transistor, and then NMOS transistor turns “OFF”. This is called discontinuous current mode.
As the output current (I_{OUT}) increases, the off-time period (t_{OFF}) of PMOS transistor runs out before I_L reaches I_{LMIN}. The next cycle starts, and PMOS transistor turns “ON” and NMOS transistor turns “OFF”, which means I_L starts increasing from I_{LMIN}. This is called continuous current mode.

When the step-down DC/DC operation is constant, I_{LMIN} and I_{LMAX} during ton of PMOS transistor would be same as during t_{OFF} of PMOS transistor. The current differential between I_{LMAX} and I_{LMIN} is described as ΔI, as the following equation 1.

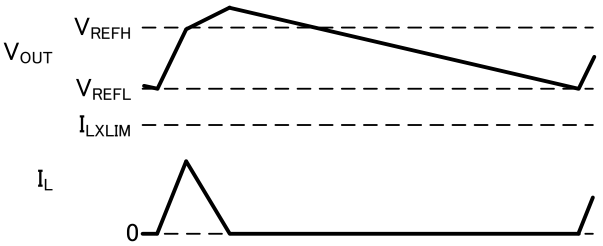
$$\Delta I = I_{LMAX} - I_{LMIN} = V_{OUT} \times t_{OPEN} / L = (V_{IN} - V_{OUT}) \times t_{ON} / L \cdots\cdots (1)$$

VFM Mode

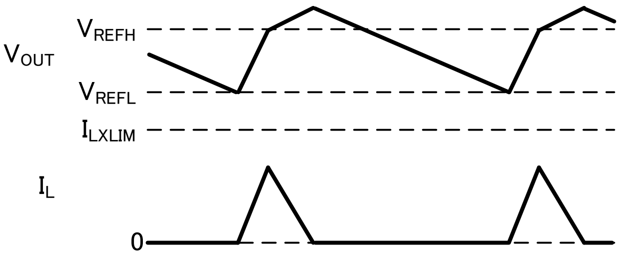
A switching method is a VFM (Variable Frequency Modulation) mode to achieve a high efficiency during light load conditions. A switching frequency varies depending on values of input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}). Check the actual characteristics for concerns regarding the switching noise.

A switching starts when V_{OUT} drops below the lower-limit reference voltage (V_{REFL}). When V_{OUT} exceeds the upper-limit reference voltage (V_{REFH}), a constant voltage outputs by a hysteresis control which stops the switching.

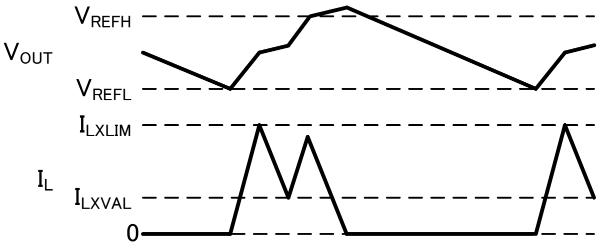
In order not to exceed the rated current of inductor or to avoid using the deteriorated band frequency of DC superimposed characteristics, the operation shifts to off-cycle once when the inductor current (I_L) exceeds LX current limit (I_{LXLIM}), and then it shifts back to on-cycle again when I_L drops below the valley current limit (I_{LXVAL}).



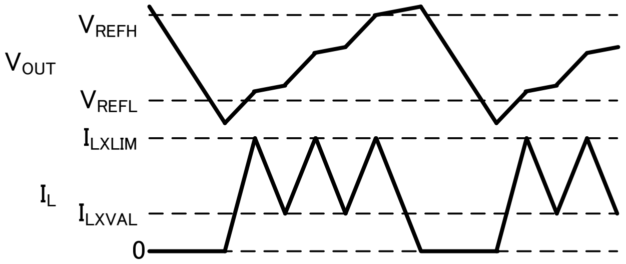
No Load



Light Load



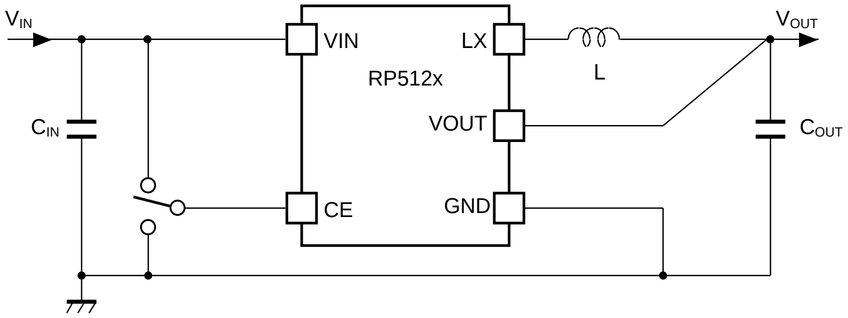
Medium Load



Heavy Load

APPLICATION INFORMATION

Typical Application



RP512x Typical Application

Recommended External Components

Symbol	Descriptions
C_{IN}	10 µF, GRM155R60J106ME44D, MURATA
C_{OUT}	22 µF, JMK107BBJ226MA-T, TAIYO
L	2.2 µH, DFE201610P-2R2M, TOKO

Precautions for Selecting External Components

- Using ceramic capacitors with low ESR (Equivalent Series Resistance) are recommended. Select capacitors with considerations of bias characteristics and input/output voltages.

- When a built-in Lx switch is turned off, a spike-like high voltage may be generated due to an action of an inductor. Using 1.5 times or more of a set output voltage is recommended for the withstanding voltage of C_{OUT}.

- Select an inductor that has small DC resistance, has sufficient allowable current and is hard to cause magnetic saturation.

TECHNICAL NOTES

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed a rated voltage, a rated current or a rated power. When designing a peripheral circuit, please be fully aware of the following points. Refer to *PCB Layout* below.

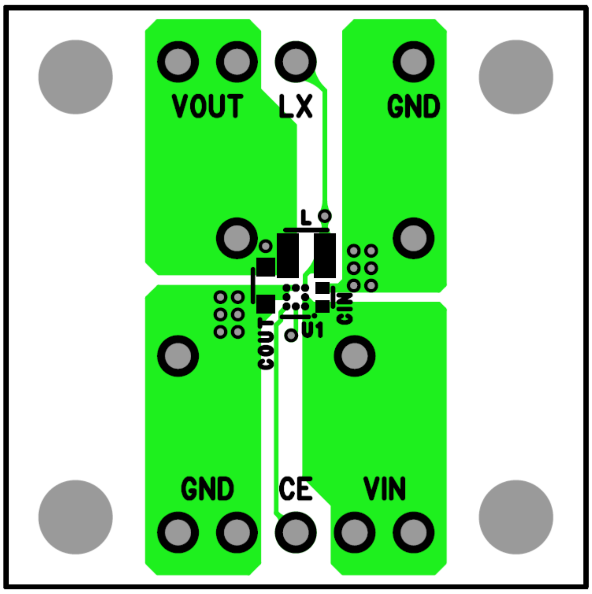
- External components must be connected as close as possible to the ICs and make wiring as short as possible. Especially, the capacitor connected in between VIN pin and GND pin must be wiring the shortest.
- If the impedance of power supply lines and GND lines is high, the internal voltage of the IC may shift by the switching current, and the operating may be unstable. Make the power supply and GND lines sufficient.
- A sufficient consideration is required due to a large switching current flows through power supply lines, GND lines, an inductor, Lx, and V_{OUT} line.
- The wiring between VOUT pin and inductor should be separated from the wiring connected to the load.
- When an intermediate voltage other than V_{IN} or GND is input to the CE pin, a supply current may be increased with a through current of a logic circuit in the IC. The CE pin is neither pulled up nor pulled down, therefore an operation is not stable at open.

RP512Zxx1x-TR-F is discontinued product.

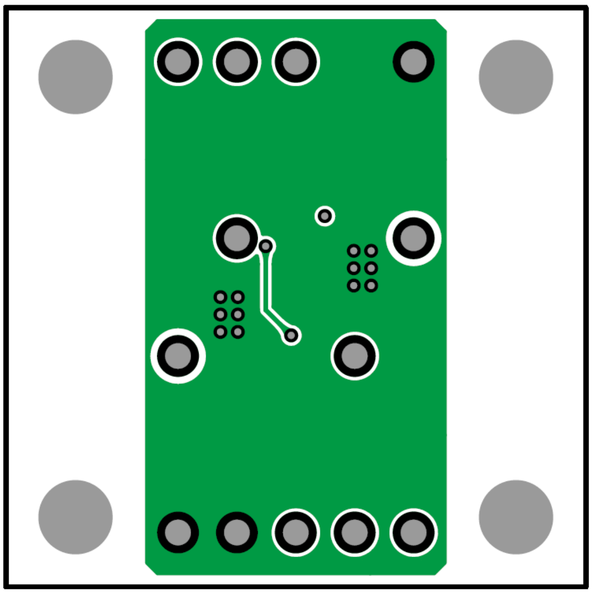
PCB Layout

RP512Zxx1x (WLCSP-8-P1)

Top Layer

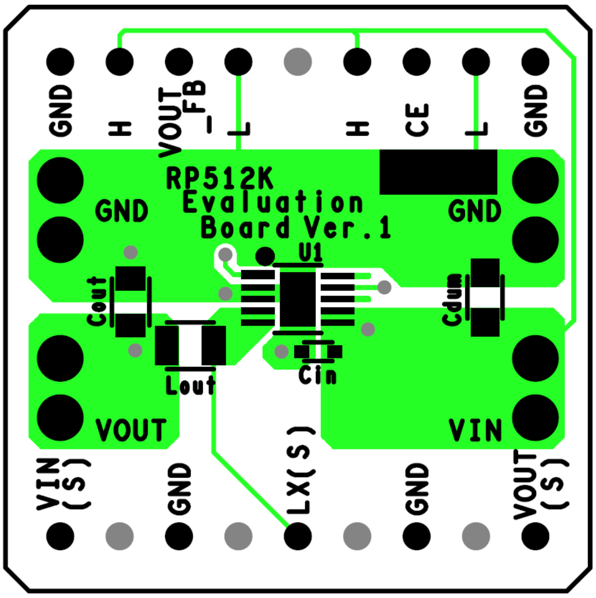


Bottom Layer

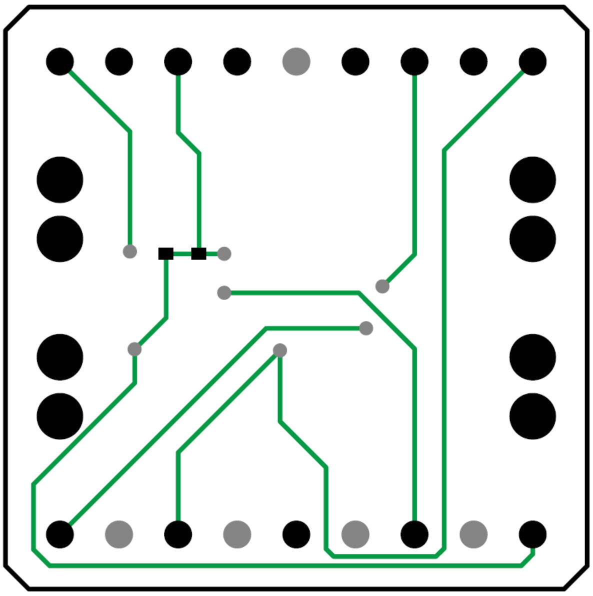


RP512Kxx1x [DFN(PL)2527-10]

Top Layer

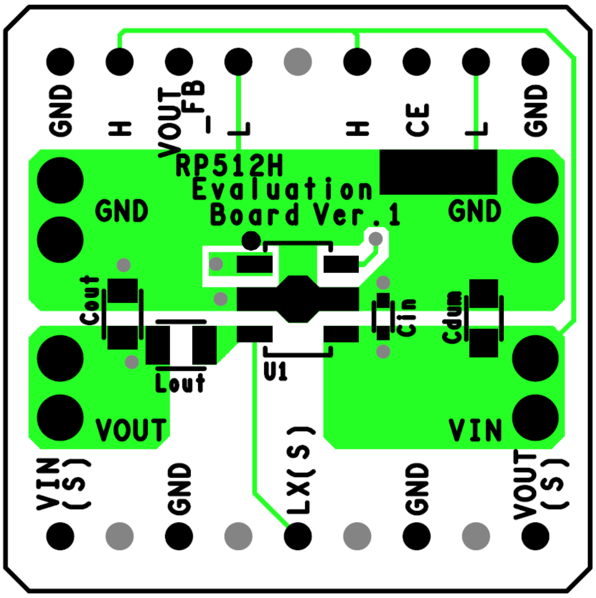


Bottom Layer

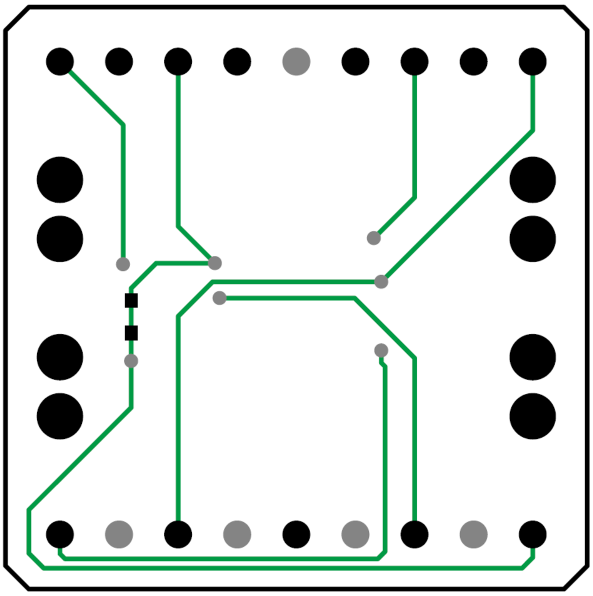


RP512Hxx1x (SOT-89-5)

Top Layer



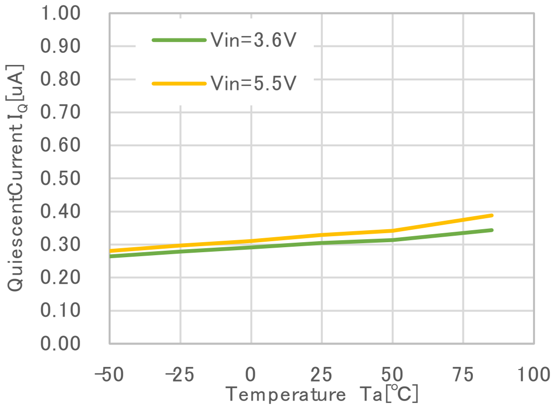
Bottom Layer



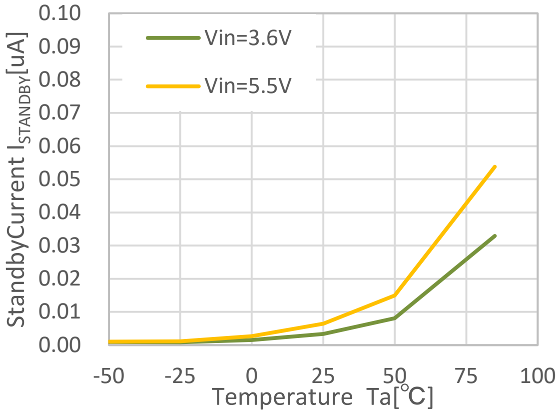
TYPICAL CHARACTERISTICS

Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Quiescent Current vs. Temperature

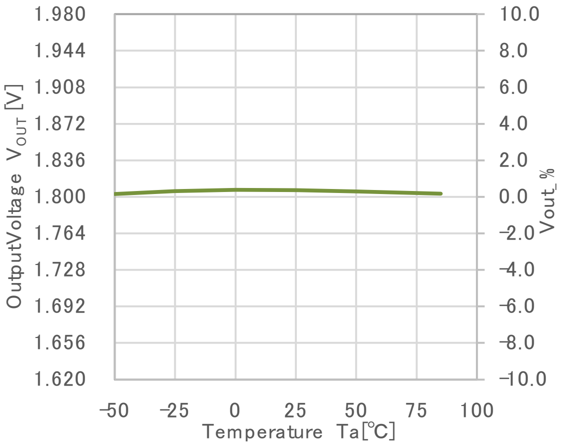


2) Standby Current vs. Temperature



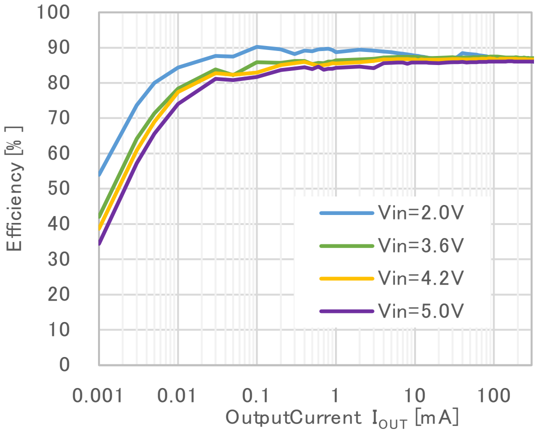
3) Output Voltage vs. Temperature

RP512x181x, V_{IN} = 3.6 V

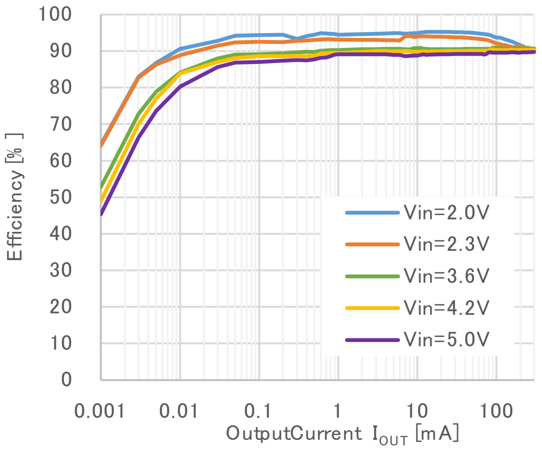


4) Efficiency vs. Output Current

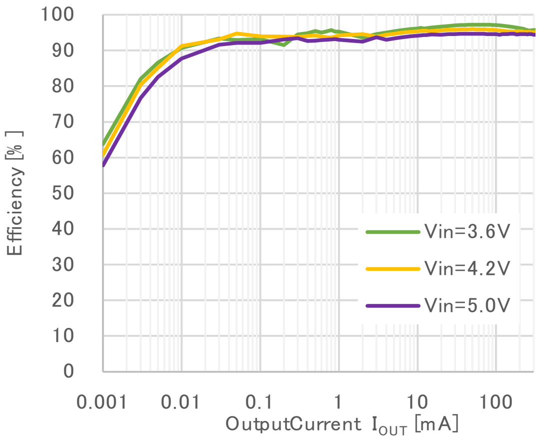
RP512x121x, Ta = 25°C



RP512x181x, Ta = 25°C

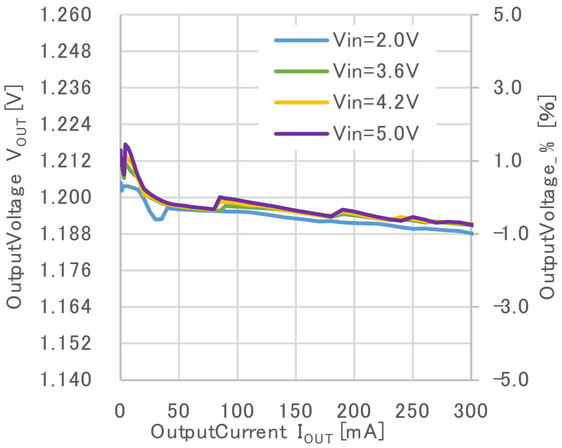


RP512x331x, Ta = 25°C

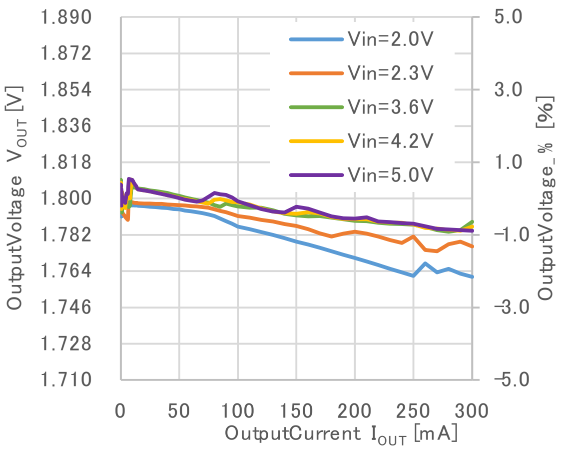


5) Output Voltage vs. Output Current

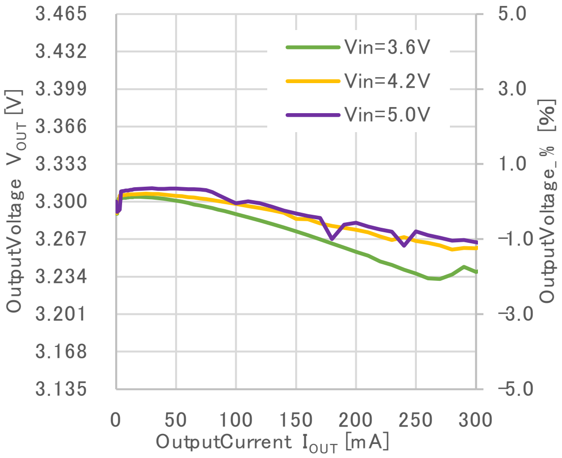
RP512x121x, Ta = 25°C



RP512x181x, Ta = 25°C



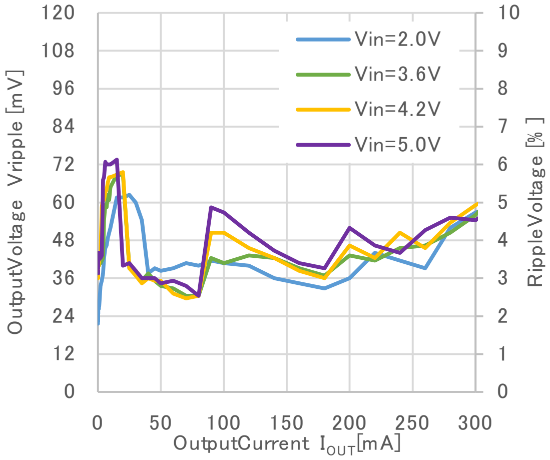
RP512x331x, Ta = 25°C



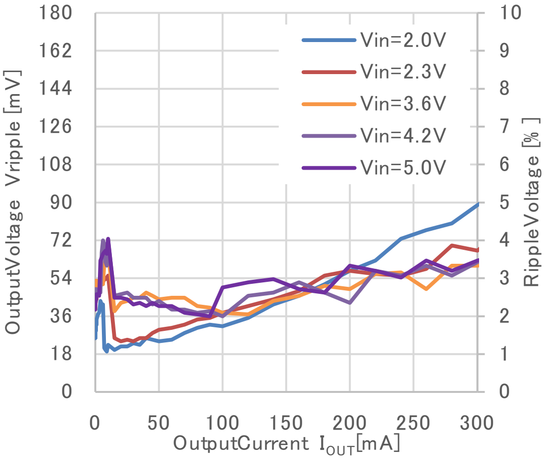
RP512Zxx1x-TR-F is discontinued product.

6) Ripple Voltage vs. Output Current

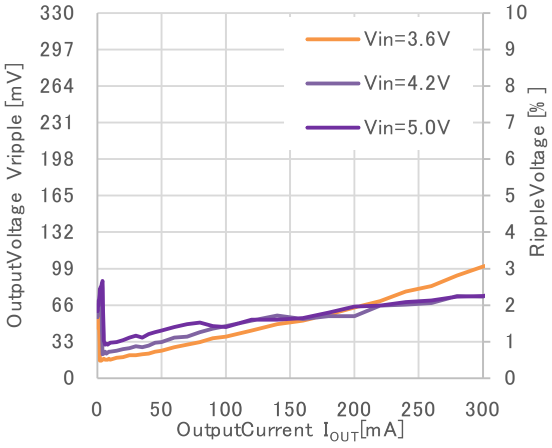
RP512x121x, Ta = 25°C



RP512x181x, Ta = 25°C

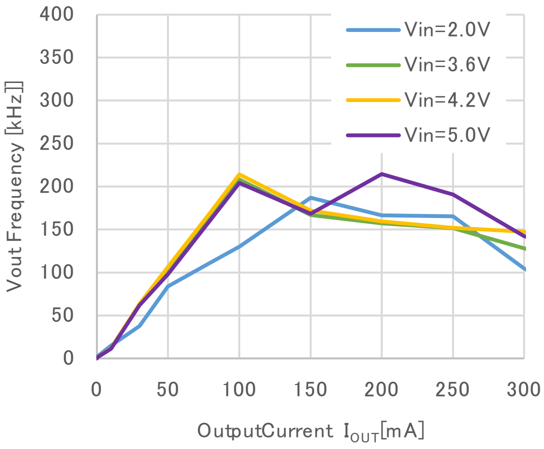


RP512x331x, Ta = 25°C

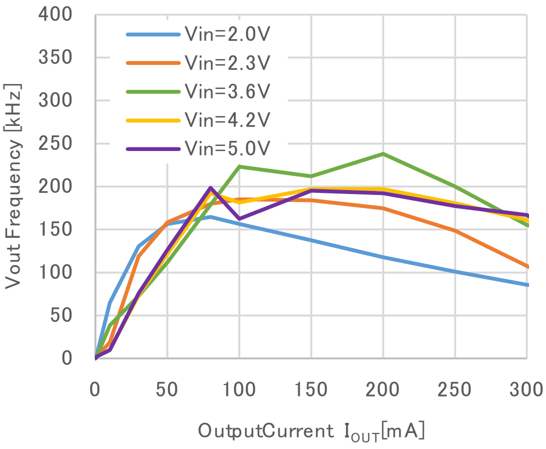


7) Switching Frequency vs. Output Current

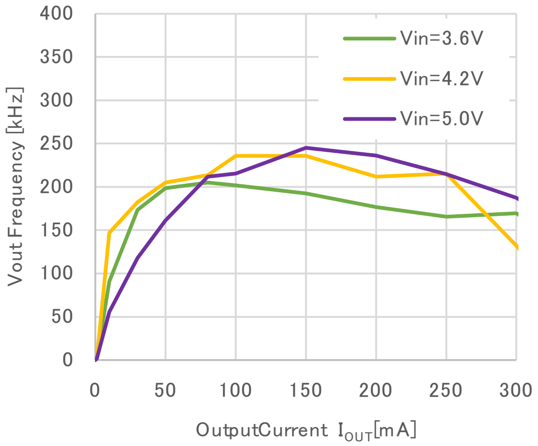
RP512x121x, Ta = 25°C



RP512x181x, Ta = 25°C



RP512x331x, Ta = 25°C

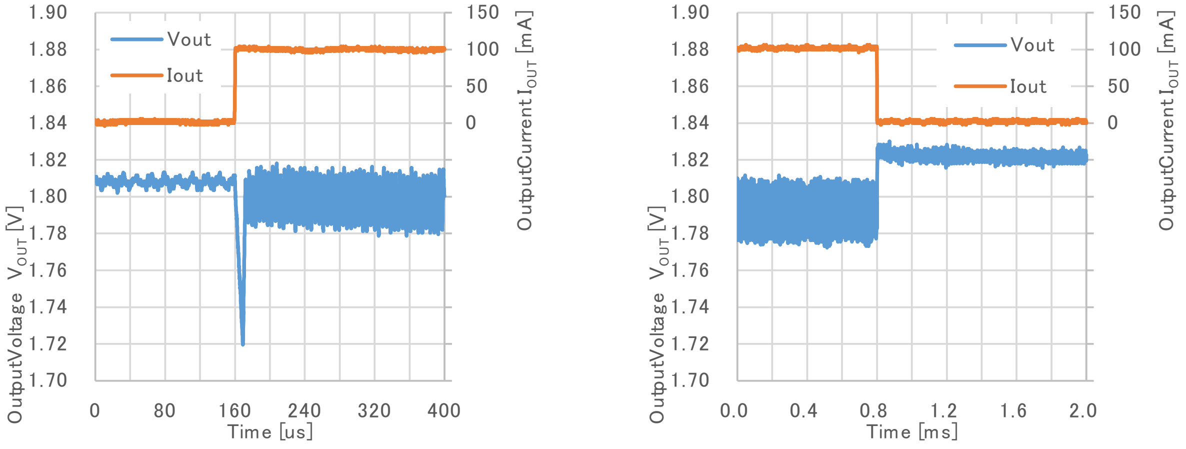


8) Load Transient Response

RP512x181x, Ta = 25°C, V_{IN} = 3.6 V

I_{OUT} = 0.01 mA -> 100 mA

I_{OUT} = 100 mA -> 0.01 mA

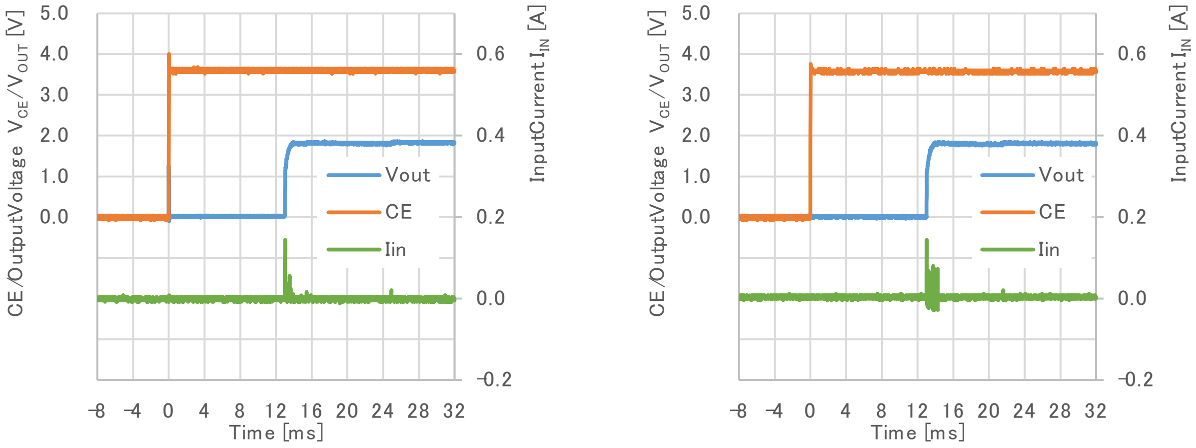


9) Soft Start Time

RP512x181x, Ta = 25°C

V_{IN} = V_{CE} =0 V -> 3.6 V, ⊿t = 10 µs

V_{IN} = 3.6 V, V_{CE} = 0 V -> 3.6 V, ⊿t = 10 µs



POWER DISSIPATION WLCSP-8-P1

Ver. B

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-9.

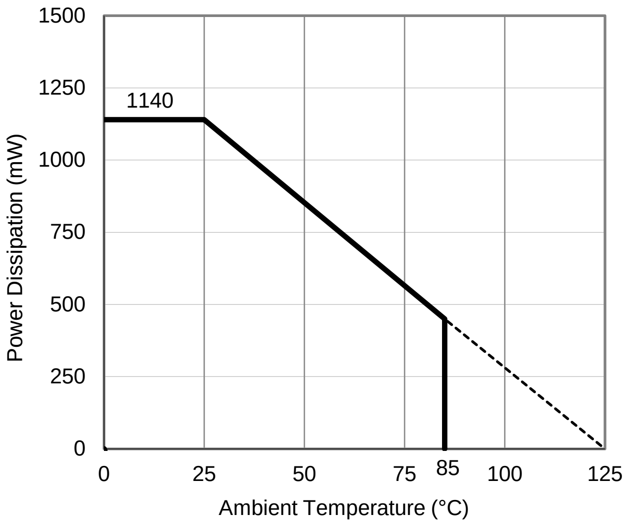
Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	101.5 mm x 114.5 mm x 1.6 mm
Copper Ratio	Outer Layers (First and Fourth Layers): 60% Inner Layers (Second and Third Layers): 100%

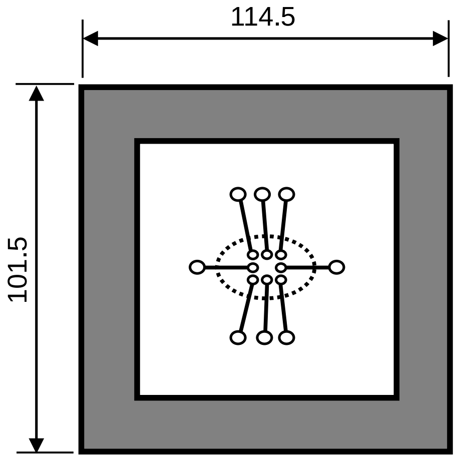
Measurement Result (Ta = 25°C, Tjmax = 125°C)

Item	Measurement Result
Power Dissipation	1140 mW
Thermal Resistance (θja)	θja = 87°C/W

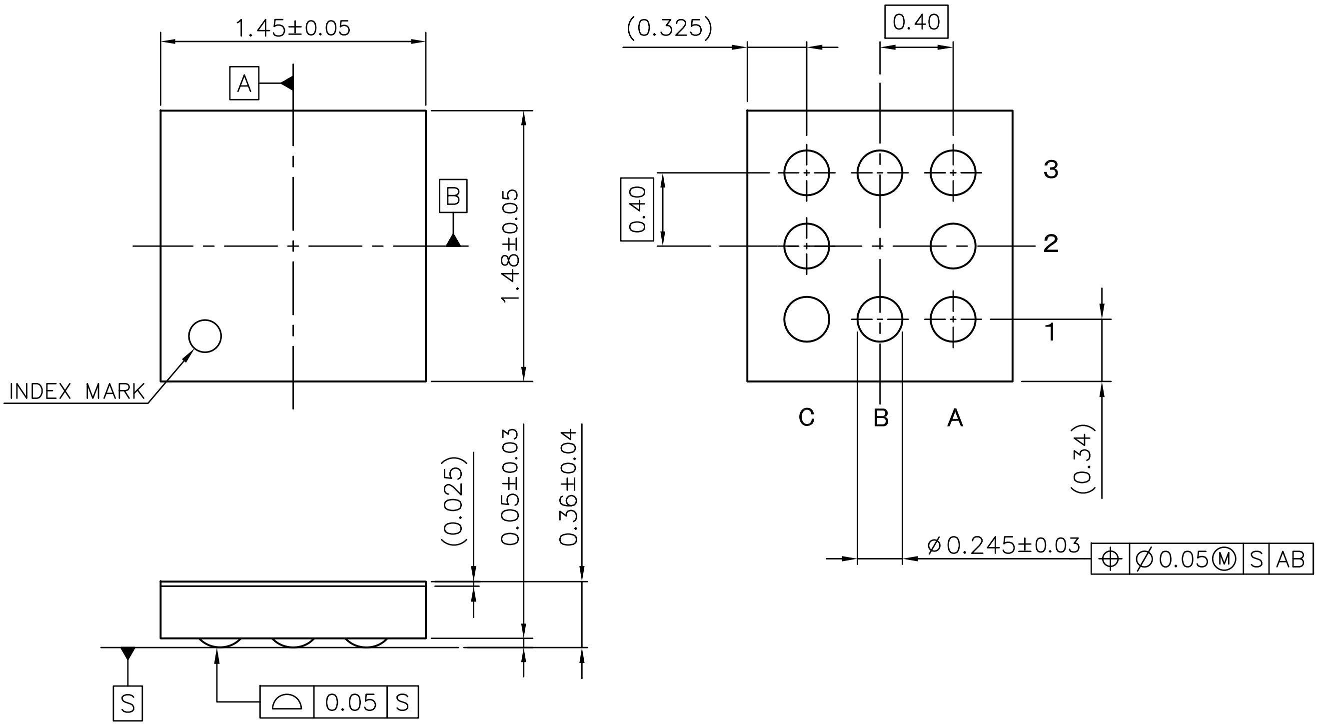
θja: Junction-to-Ambient Thermal Resistance



Power Dissipation vs. Ambient Temperature



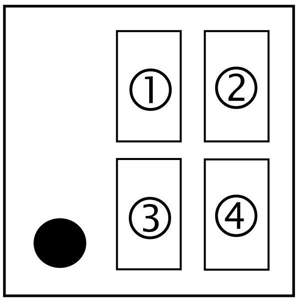
Measurement Board Pattern



WLCSP-8-P1 Package Dimensions (Unit: mm)

MK-RP512Z-JE-B

①②: Product Code ··· Refer to *Part Marking List*
③④: Lot Number ··· Alphanumeric Serial Number



WLCSP-8-P1 Part Markings

NOTICE
There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or distributor before attempting to use AOI.

MK-RP512Z-JE-B

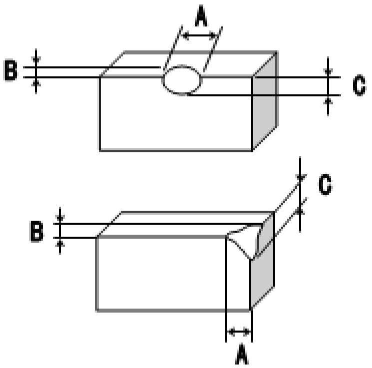
RP512Zxx1C/RP512Zxx1D Part Marking List

Product Name	①	②
RP512Z101C	5	A
RP512Z111C	5	C
RP512Z121C	5	E
RP512Z131C	5	F
RP512Z141C	5	G
RP512Z151C	5	H
RP512Z161C	5	J
RP512Z171C	5	K
RP512Z181C	5	L
RP512Z191C	5	N
RP512Z201C	5	P
RP512Z211C	5	R
RP512Z221C	5	T
RP512Z231C	5	U
RP512Z241C	5	V
RP512Z251C	5	X
RP512Z261C	5	Y
RP512Z271C	6	A
RP512Z281C	6	C
RP512Z291C	6	E
RP512Z301C	6	F
RP512Z311C	6	G
RP512Z321C	6	H
RP512Z331C	6	J
RP512Z341C	6	K
RP512Z351C	6	L
RP512Z361C	6	N
RP512Z371C	6	P
RP512Z381C	6	R
RP512Z391C	6	T
RP512Z401C	6	U

Product Name	①	②
RP512Z101D	7	A
RP512Z111D	7	C
RP512Z121D	7	E
RP512Z131D	7	F
RP512Z141D	7	G
RP512Z151D	7	H
RP512Z161D	7	J
RP512Z171D	7	K
RP512Z181D	7	L
RP512Z191D	7	N
RP512Z201D	7	P
RP512Z211D	7	R
RP512Z221D	7	T
RP512Z231D	7	U
RP512Z241D	7	V
RP512Z251D	7	X
RP512Z261D	7	Y
RP512Z271D	8	A
RP512Z281D	8	C
RP512Z291D	8	E
RP512Z301D	8	F
RP512Z311D	8	G
RP512Z321D	8	H
RP512Z331D	8	J
RP512Z341D	8	K
RP512Z351D	8	L
RP512Z361D	8	N
RP512Z371D	8	P
RP512Z381D	8	R
RP512Z391D	8	T
RP512Z401D	8	U

Visual Inspection Criteria WLCSP

VI-160823

No.	Inspection Items	Inspection Criteria	Figure
1	Package chipping	A≥0.2mm is rejected B≥0.2mm is rejected C≥0.2mm is rejected And, Package chipping to Si surface and to bump is rejected.	
2	Si surface chipping	A≥0.2mm is rejected B≥0.2mm is rejected C≥0.2mm is rejected But, even if A≥0.2mm, B≤0.1mm is acceptable.	
3	No bump	No bump is rejected.	
4	Marking miss	To reject incorrect marking, such as another product name marking or another lot No. marking.	
5	No marking	To reject no marking on the package.	
6	Reverse direction of marking	To reject reverse direction of marking character.	
7	Defective marking	To reject unreadable marking. (Microscope: X15/ White LED/ Viewed from vertical direction)	
8	Scratch	To reject unreadable marking character by scratch. (Microscope: X15/ White LED/ Viewed from vertical direction)	
9	Stain and Foreign material	To reject unreadable marking character by stain and foreign material. (Microscope: X15/ White LED/ Viewed from vertical direction)	

POWER DISSIPATION DFN(PL)2527-10

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

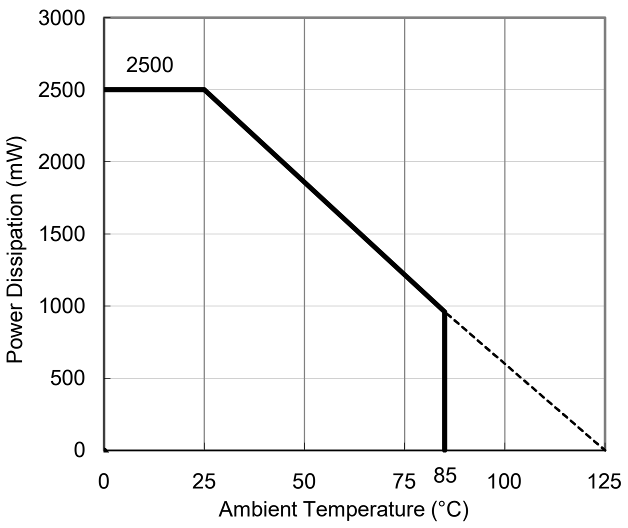
Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	ϕ 0.3 mm × 30 pcs

Measurement Result (Ta = 25°C, Tjmax = 125°C)

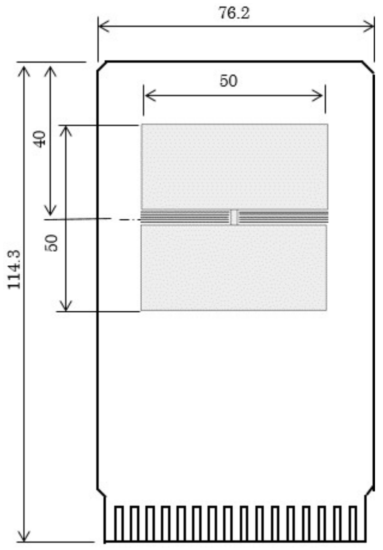
Item	Measurement Result
Power Dissipation	2500 mW
Thermal Resistance (θja)	θja = 39°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 11°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



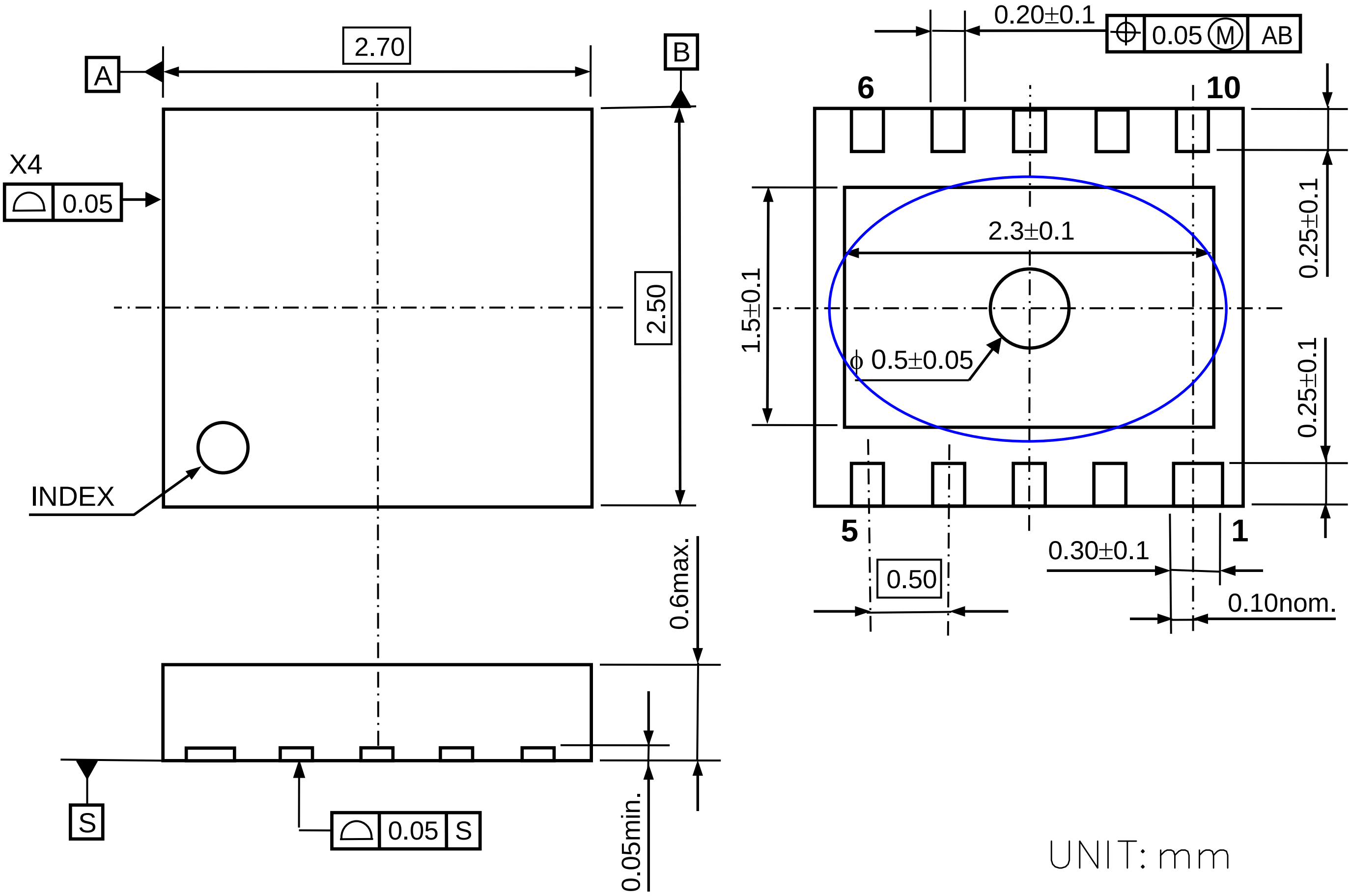
Power Dissipation vs. Ambient Temperature



Measurement Board Pattern

PACKAGE DIMENSIONS DFN(PL)2527-10

Ver. A



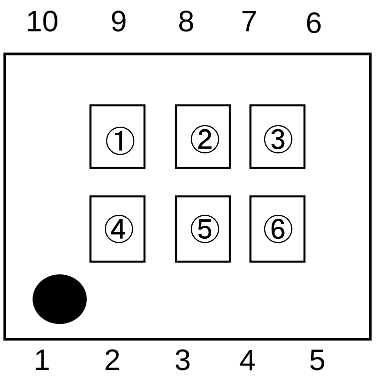
DFN(PL)2527-10 Package Dimensions

∗ The tab on the bottom of the package is substrate level (GND). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.

MK-RP512K-JE-A

①②③④: Product Code ··· Refer to *Part Marking List*

⑤⑥: Lot Number ··· Alphanumeric Serial Number



RP512K [DFN(PL)2527-10] Part Markings

NOTICE
There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or distributor before attempting to use AOI.

MK-RP512K-JE-A

RP512Kxx1C / RP512Kxx1D Part Making List

Product Name	①②③④
RP512K101C	F V 1 0
RP512K111C	F V 1 1
RP512K121C	F V 1 2
RP512K131C	F V 1 3
RP512K141C	F V 1 4
RP512K151C	F V 1 5
RP512K161C	F V 1 6
RP512K171C	F V 1 7
RP512K181C	F V 1 8
RP512K191C	F V 1 9
RP512K201C	F V 2 0
RP512K211C	F V 2 1
RP512K221C	F V 2 2
RP512K231C	F V 2 3
RP512K241C	F V 2 4
RP512K251C	F V 2 5
RP512K261C	F V 2 6
RP512K271C	F V 2 7
RP512K281C	F V 2 8
RP512K291C	F V 2 9
RP512K301C	F V 3 0
RP512K311C	F V 3 1
RP512K321C	F V 3 2
RP512K331C	F V 3 3
RP512K341C	F V 3 4
RP512K351C	F V 3 5
RP512K361C	F V 3 6
RP512K371C	F V 3 7
RP512K381C	F V 3 8
RP512K391C	F V 3 9
RP512K401C	F V 4 0

Product Name	①②③④
RP512K101D	F W 1 0
RP512K111D	F W 1 1
RP512K121D	F W 1 2
RP512K131D	F W 1 3
RP512K141D	F W 1 4
RP512K151D	F W 1 5
RP512K161D	F W 1 6
RP512K171D	F W 1 7
RP512K181D	F W 1 8
RP512K191D	F W 1 9
RP512K201D	F W 2 0
RP512K211D	F W 2 1
RP512K221D	F W 2 2
RP512K231D	F W 2 3
RP512K241D	F W 2 4
RP512K251D	F W 2 5
RP512K261D	F W 2 6
RP512K271D	F W 2 7
RP512K281D	F W 2 8
RP512K291D	F W 2 9
RP512K301D	F W 3 0
RP512K311D	F W 3 1
RP512K321D	F W 3 2
RP512K331D	F W 3 3
RP512K341D	F W 3 4
RP512K351D	F W 3 5
RP512K361D	F W 3 6
RP512K371D	F W 3 7
RP512K381D	F W 3 8
RP512K391D	F W 3 9
RP512K401D	F W 4 0

POWER DISSIPATION SOT-89-5

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	ϕ 0.3 mm × 13 pcs

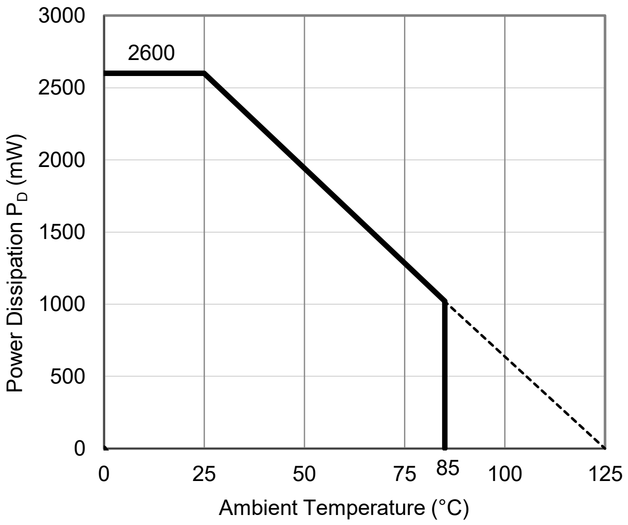
Measurement Result

(Ta = 25°C, Tjmax = 125°C)

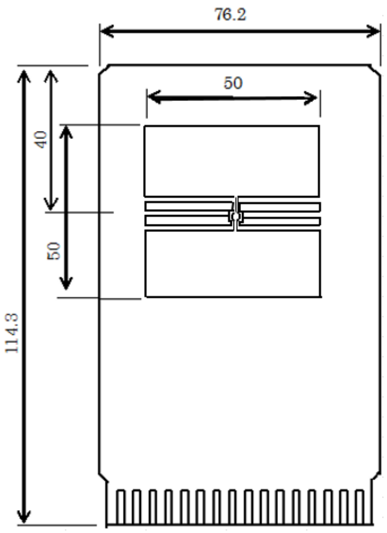
Item	Measurement Result
Power Dissipation	2600 mW
Thermal Resistance (θja)	θja = 38°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 13°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



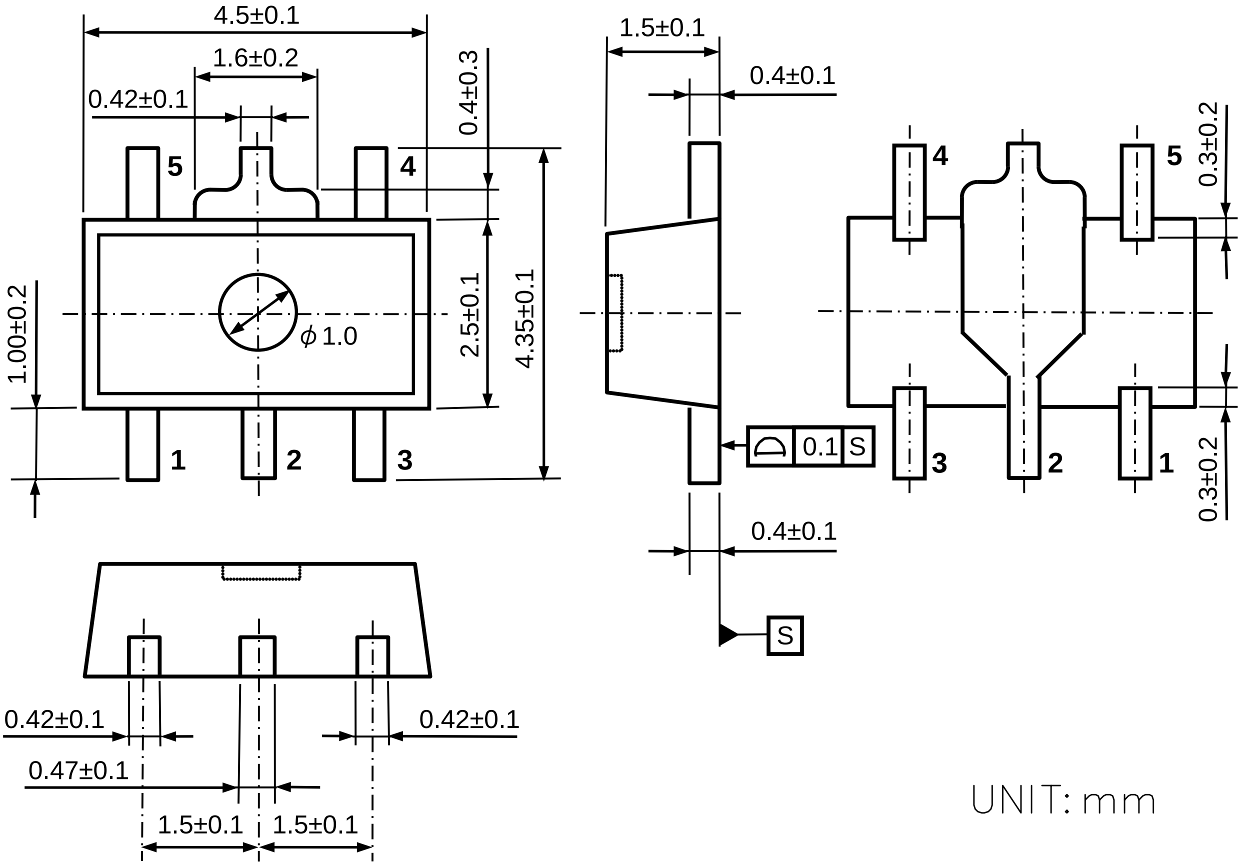
Power Dissipation vs. Ambient Temperature



Measurement Board Pattern

PACKAGE DIMENSIONS SOT-89-5

Ver. A

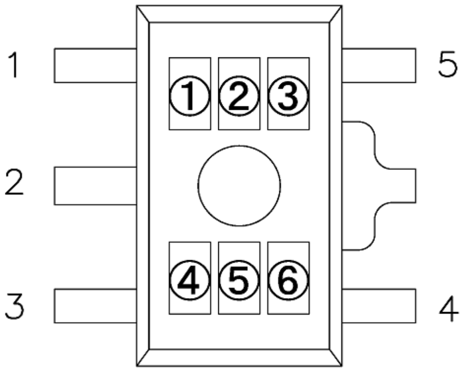


UNIT: mm

SOT-89-5 Package Dimensions

MK-RP512H-JE-A

①②③④: Product Code ··· Refer to *Part Marking List*
⑤⑥: Lot Number ··· Alphanumeric Serial Number



RP512H (SOT-89-5) Part Markings

NOTICE
There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or distributor before attempting to use AOI.

RP512Hxx1C / RP512Hxx1D Part Marking List

Product Name	①②③④
RP512H101C	M10C
RP512H111C	M11C
RP512H121C	M12C
RP512H131C	M13C
RP512H141C	M14C
RP512H151C	M15C
RP512H161C	M16C
RP512H171C	M17C
RP512H181C	M18C
RP512H191C	M19C
RP512H201C	M20C
RP512H211C	M21C
RP512H221C	M22C
RP512H231C	M23C
RP512H241C	M24C
RP512H251C	M25C
RP512H261C	M26C
RP512H271C	M27C
RP512H281C	M28C
RP512H291C	M29C
RP512H301C	M30C
RP512H311C	M31C
RP512H321C	M32C
RP512H331C	M33C
RP512H341C	M34C
RP512H351C	M35C
RP512H361C	M36C
RP512H371C	M37C
RP512H381C	M38C
RP512H391C	M39C
RP512H401C	M40C

Product Name	①②③④
RP512H101D	M10D
RP512H111D	M11D
RP512H121D	M12D
RP512H131D	M13D
RP512H141D	M14D
RP512H151D	M15D
RP512H161D	M16D
RP512H171D	M17D
RP512H181D	M18D
RP512H191D	M19D
RP512H201D	M20D
RP512H211D	M21D
RP512H221D	M22D
RP512H231D	M23D
RP512H241D	M24D
RP512H251D	M25D
RP512H261D	M26D
RP512H271D	M27D
RP512H281D	M28D
RP512H291D	M29D
RP512H301D	M30D
RP512H311D	M31D
RP512H321D	M32D
RP512H331D	M33D
RP512H341D	M34D
RP512H351D	M35D
RP512H361D	M36D
RP512H371D	M37D
RP512H381D	M38D
RP512H391D	M39D
RP512H401D	M40D

1. The products and the product specifications described in this document are subject to change or discontinuation of production without notice for reasons such as improvement. Therefore, before deciding to use the products, please refer to our sales representatives for the latest information thereon.
2. The materials in this document may not be copied or otherwise reproduced in whole or in part without the prior written consent of us.
3. This product and any technical information relating thereto are subject to complementary export controls (so-called KNOW controls) under the Foreign Exchange and Foreign Trade Law, and related politics ministerial ordinance of the law. (Note that the complementary export controls are inapplicable to any application-specific products, except rockets and pilotless aircraft, that are insusceptible to design or program changes.) Accordingly, when exporting or carrying abroad this product, follow the Foreign Exchange and Foreign Trade Control Law and its related regulations with respect to the complementary export controls.
4. The technical information described in this document shows typical characteristics and example application circuits for the products. The release of such information is not to be construed as a warranty of or a grant of license under our or any third party's intellectual property rights or any other rights.
5. The products listed in this document are intended and designed for use as general electronic components in standard applications (office equipment, telecommunication equipment, measuring instruments, consumer electronic products, amusement equipment etc.). Those customers intending to use a product in an application requiring extreme quality and reliability, for example, in a highly specific application where the failure or misoperation of the product could result in human injury or death should first contact us.
    - Aerospace Equipment
    - Equipment Used in the Deep Sea
    - Power Generator Control Equipment (nuclear, steam, hydraulic, etc.)
    - Life Maintenance Medical Equipment
    - Fire Alarms / Intruder Detectors
    - Vehicle Control Equipment (automotive, airplane, railroad, ship, etc.)
    - Various Safety Devices
    - Traffic control system
    - Combustion equipment

    In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.
6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
8. Quality Warranty

    8-1. Quality Warranty Period

    In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.

    8-2. Quality Warranty Remedies

    When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

    Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.

    8-3. Remedies after Quality Warranty Period

    With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
9. Anti-radiation design is not implemented in the products described in this document.
10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.

Nisshinbo Micro Devices Inc.

Official website
https://www.nisshinbo-microdevices.co.jp/en/

Purchase information
https://www.nisshinbo-microdevices.co.jp/en/buy/